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APPLICATION NO.	FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/530,063	03/31/2005		Philippe Meunier-Beillard	BE02 0027 US	6267	
65913 NXP, B.V.	7590	12/12/2007	-	EXAM	EXAMINER	
NXP INTELI	LECTUAL F	ESTRADA,	ESTRADA, MICHELLE			
M/S41-SJ 1109 MCKA	Y DRIVE		ART UNIT	PAPER NUMBER		
SAN JOSE, C	CA 95131		2823			
				NOTIFICATION DATE	DELIVERY MODE	
				12/12/2007	ELECTRONIC	

## Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

ip.department.us@nxp.com

•				M.	
		Application No.	Applicant(s)		
		10/530,063	MEUNIER-BEILLARD ET AL.		
	Office Action Summary	Examiner	Art Unit		
		Michelle Estrada	2823		
Period fo	The MAILING DATE of this communication ap or Reply	pears on the cover sheet with the	e correspondence address		
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPL CHEVER IS LONGER, FROM THE MAILING D nsions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period are to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	OATE OF THIS COMMUNICATION 136(a). In no event, however, may a reply be will apply and will expire SIX (6) MONTHS free, cause the application to become ABANDO	ON.  e timely filed  rom the mailing date of this communication.  INED (35 U.S.C. § 133).		
Status					
1)⊠	Responsive to communication(s) filed on 02 C	October 2007.			
2a) <u></u>	This action is <b>FINAL</b> . 2b) This action is non-final.				
3)□	Since this application is in condition for allowa	ance except for formal matters,	prosecution as to the merits is		
	closed in accordance with the practice under	Ex parte Quayle, 1935 C.D. 11,	453 O.G. 213.		
Disposit	ion of Claims				
4)⊠	Claim(s) 4,5,7,18 and 19 is/are pending in the	e application.			
	4a) Of the above claim(s) is/are withdra	awn from consideration.			
5)[	Claim(s) is/are allowed.				
′=	Claim(s) 4,7 and 18 is/are rejected.				
•	Claim(s) <u>5 and 19</u> is/are objected to.				
8)	Claim(s) are subject to restriction and/o	or election requirement.			
Applicat	ion Papers				
9)[	The specification is objected to by the Examine	er.			
10)	The drawing(s) filed on is/are: a) acc	cepted or b) objected to by the	e Examiner.		
	Applicant may not request that any objection to the	- · · ·			
11)	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the E				
Priority	under 35 U.S.C. § 119				
-	Acknowledgment is made of a claim for foreign All b) Some * c) None of:	n priority under 35 U.S.C. § 119	l(a)-(d) or (f).		
	1. Certified copies of the priority documen	nts have been received.	·		
	2. Certified copies of the priority documen				
	3. Copies of the certified copies of the price		eived in this National Stage		
	application from the International Burea	·	:		
7	See the attached detailed Office action for a lis	it of the certified copies not rece	ived.		
Attachmei	• •	_			
$\cdot =$	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948)	4)			
3) 🔲 Info	mation Disclosure Statement(s) (PTO/SB/08) er No(s)/Mail Date	5) Notice of Inform. 6) Other:			

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### **DETAILED ACTION**

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 4, 7 and 18 are rejected under 35 U.S.C. 102(b) as being anticipated by Shiota et al. (5,879,970).

Re claim 4, Shiota et al. discloses depositing an epitaxial layer based on Group IV elements a silicon substrate by Chemical Vapor Deposition using source gases (See abstract), and including employing nitrogen as a carrier gas, wherein the epitaxial layer comprises a SiGe epitaxial layer (Abstract and Col.6, lines 15-20).

Re claim 7, Shiota et al. disclose wherein the CVD process is carried out at a temperature that facilitates a CVD growth rate of an epitaxial layer that is substantially greater than a CVD growth rate of such an epitaxial layer using hydrogen as a carrier gas, since the same temperature is being used as the present invention (less than 600 °C).

Re claim 18, Shiota et al. discloses wherein the process is carried out at a temperature of less than about 600°C (see abstract, 350 °C to 450 °C).

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# Allowable Subject Matter

Claims 5 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michelle Estrada whose telephone number is 571-272-1858. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on 571-272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 571-272-2800.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

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you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Michelle Estrada Primary Examiner Art Unit 2823

ME December 5, 2007